



CV111-3A

UMTS-band High Linearity Downconverter

CV111-3APCB75 供应商

Product Features

- High dynamic range downconverter with integrated LO, IF, & RF amps
- RF: 1900 – 2200 MHz
- IF: 65 – 300 MHz
- +38 dBm Output IP3
- +21 dBm Output P1dB
- 5.3 dB Noise Figure
- +5V Single supply operation
- Pb-free 6mm 28-pin QFN package
- Low-side LO configuration
- Common footprint with other PCS/ cellular versions

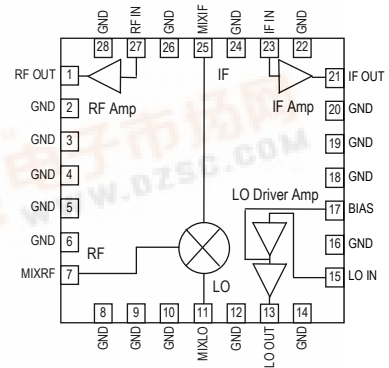
Product Description

The CV111-3A is a high linearity downconverter designed to meet the demanding issues for performance, functionality, and cost goals of current and next generation mobile infrastructure basestations. It provides high dynamic range performance in a low profile surface-mount leadless package that measures 6 x 6 mm square.

Functionality includes RF amplification, frequency conversion and IF amplification, while an integrated LO driver amplifier powers the passive mixer. The MCM is implemented with reliable and mature GaAs MESFET and InGaP HBT technology.

Typical applications include frequency down conversion, modulation and demodulation for receivers used in CDMA, CDMA2000, W-CDMA / IMT2000, GPRS, and EDGE 2.5G mobile infrastructure technologies for UMTS frequency bands.

Functional Diagram



Top View

Specifications ⁽¹⁾

Parameters	Units	Min	Typ	Max	Comments
RF Frequency Range	MHz		1900 – 2200		
LO Frequency Range	MHz		1600 – 2135		
IF Center Frequency Range	MHz		65 – 300		See note 2
% Bandwidth around IF center frequency	%		±7.5		See note 3
IF Test Frequency	MHz		240		
SSB Conversion Gain	dB		20		Temp = 25 °C
Gain Drift over Temp (-40 to 85 °C)	dB		±0.5		Referenced to +25 °C
Output IP3	dBm		+38		See note 4
Output IP2	dBm		+48		See note 4
Output 1dB Compression Point	dBm		+21		
Noise Figure	dB		5.3		See note 5
LO Input Drive Level	dBm	-2.5	0	+2.5	
LO-RF Isolation	dB		40		See note 6
LO-IF Isolation	dB		25		P _{LO} = 0 dBm
Return Loss: RF Port	dB		14		
Return Loss: LO Port	dB		14		
Return Loss: IF Port	dB		14		
Operating Supply Voltage	V	+4.9	+5	+5.1	
Supply Current	mA	290	360	480	
FIT Rating	failures / 1E9 hrs			72.1	@ 70° C ambient, 90% confidence
Thermal Resistance	°C / W			27	
Junction Temperature	°C			160	See note 7

1. Specifications when using the application specific circuit (shown on page 3) with a low side LO = 0 dBm in a downconverting application over the operating case temperature range.
2. IF matching components affect the center IF frequency. Proper component values for other IF center frequencies than shown can be provided by emailing to applications.engineering@wj.com.
3. The IF bandwidth of the converter is defined as 15% around any center frequency in its operating IF frequency range. The bandwidth is determined with external components. Specifications are valid around the total ±7.5% bandwidth, i.e. with a center frequency of 80 MHz, the specifications are valid from 80 ± 6 MHz.
4. Assumes the supply voltage = +5 V. OIP3 is measured with $\Delta f = 1$ MHz with IF_{out} = 5 dBm / tone.
5. Assumes LO injection noise is filtered at the thermal noise floor, -174 dBm/Hz, at the RF, IF, and Image frequencies.
6. L-R Isolation is referenced to an LO injection of 0 dBm. The L-R performance shown also includes the isolation due to an external SAW filter between the RF amplifier and mixer.
7. The maximum junction temperature ensures a minimum MTTF rating of 1 million hours of usage.

Absolute Maximum Rating

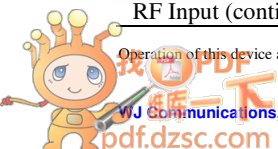
Parameter	Rating
Operating Case Temperature	-40 to +85° C
Storage Temperature	-55 to +125° C
DC Voltage	+6 V
Junction Temperature	+220 °C
RF Input (continuous)	+2 dBm

Ordering Information

Part No.	Description
CV111-3AF	UMTS-band High Linearity Downconverter (lead-free/RoHS-compliant 6x6mm QFN package)
CV111-3APCB75	Fully Assembled Eval. Board, IF = 75MHz
CV111-3APCB240	Fully Assembled Eval. Board, IF = 240MHz

Operation of this device above any of these parameters may cause permanent damage.

Specifications and information are subject to change without notice





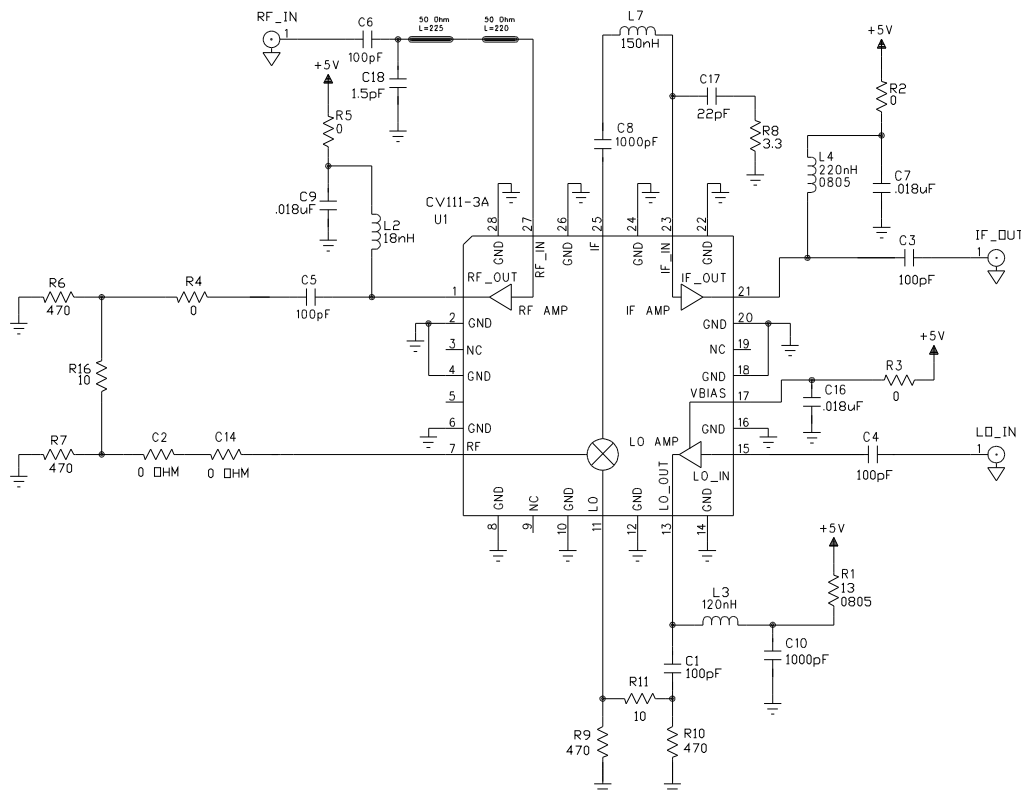
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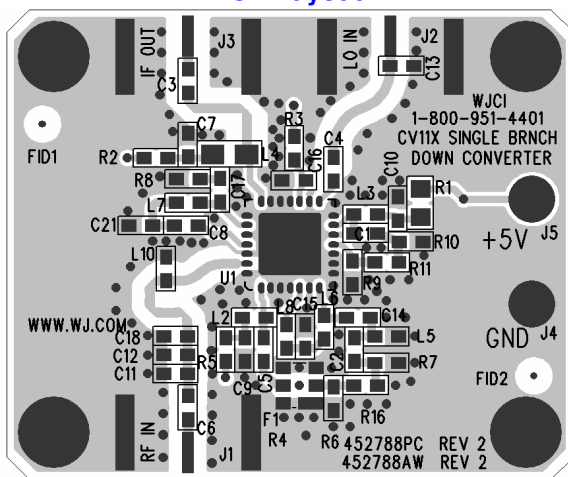
UMTS-band High Linearity Downconverter

Downconverting Application Circuit: CV111-3APCB75

RF = 1900 – 2200 MHz, IF = 75 MHz



PCB Layout



Circuit Board Material: .014" FR-4, 4 layers, .062" total thickness

Bill of Materials

Ref. Desig.	Component
R1	13 Ω chip resistor, size 0805
R2, R3, R4, R5, C2, C14	0 Ω chip resistor
R6, R7, R9, R10	470 Ω chip resistor
R8	3.3 Ω chip resistor
R11, R16	10 Ω chip resistor
C1, C3, C4, C5, C6	100 pF chip capacitor
C7, C9, C16	0.018 μ F chip capacitor
C8, C10	1000 pF chip capacitor
C11, C12, C13, C15, C21, F1, L5, L6, L8, L10	Shown in silkscreen, but not used in actual circuit.
C17	22 pF chip capacitor
C18	1.5 pF chip capacitor
L2	18 nH chip inductor
L3	120 nH chip inductor
L4	220 nH chip inductor, size 0805
L7	22 nH chip inductor
U1	CV111-3A WJ Converter

All components are of size 0603 unless otherwise specified.



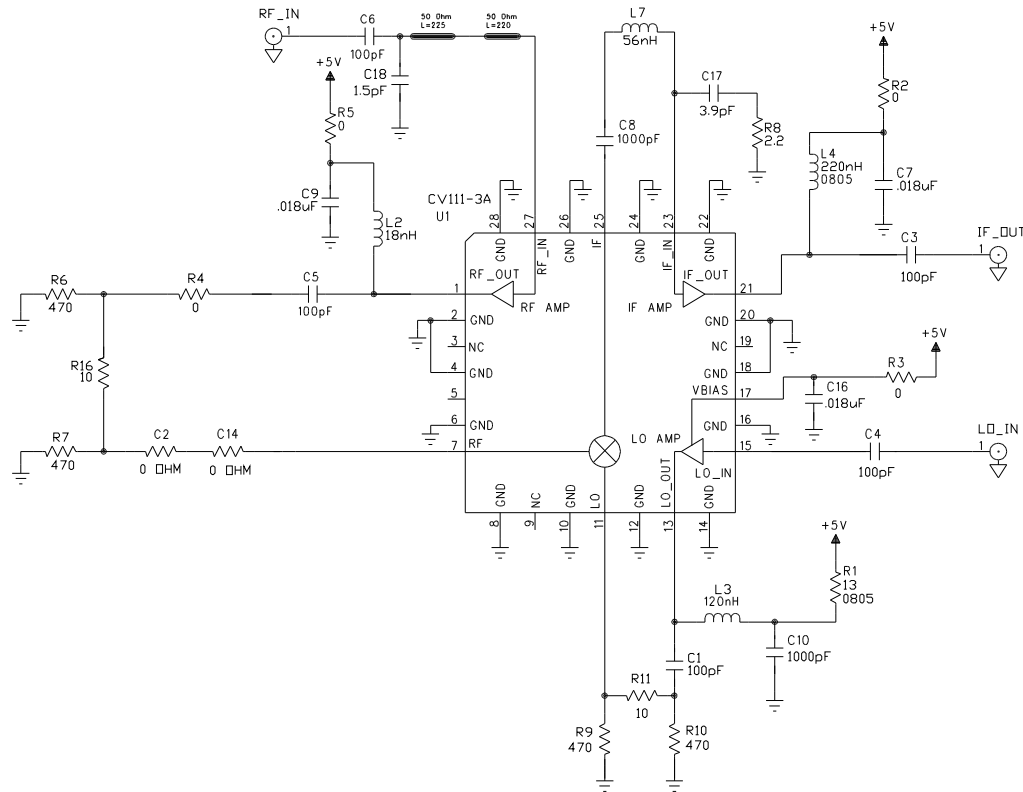
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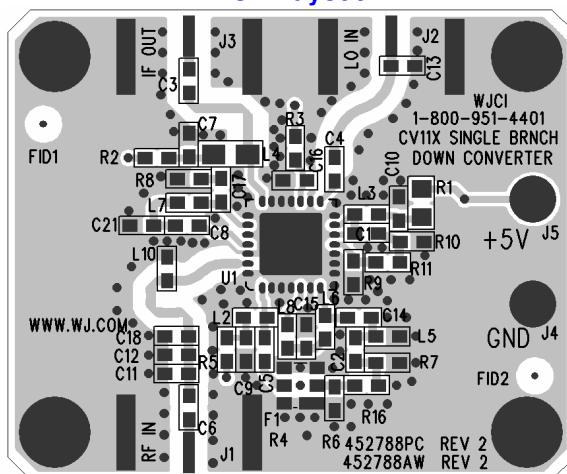
UMTS-band High Linearity Downconverter

Downconverting Application Circuit: CV111-3APCB240

RF = 1900 – 2200 MHz, IF = 240 MHz



PCB Layout



Circuit Board Material: .014" FR-4, 4 layers, .062" total thickness

Bill of Materials

Ref. Desig.	Component
R1	13 Ω chip resistor, size 0805
R2, R3, R4, R5, C2, C14	0 Ω chip resistor
R6, R7, R9, R10	470 Ω chip resistor
R8	2.2 Ω chip resistor
R11, R16	10 Ω chip resistor
C1, C3, C4, C5, C6	100 pF chip capacitor
C7, C9, C16	0.018 μ F chip capacitor
C8, C10	1000 pF chip capacitor
C11, C12, C13, C15, C21, F1, L5, L6, L8, L10	Shown in silkscreen, but not used in actual circuit.
C17	3.9 pF chip capacitor
C18	1.5 pF chip capacitor
L2	18 nH chip inductor
L3	120 nH chip inductor
L4	220 nH chip inductor, size 0805
L7	56 nH chip inductor
U1	CV111-3A WJ Converter

All components are of size 0603 unless otherwise specified.



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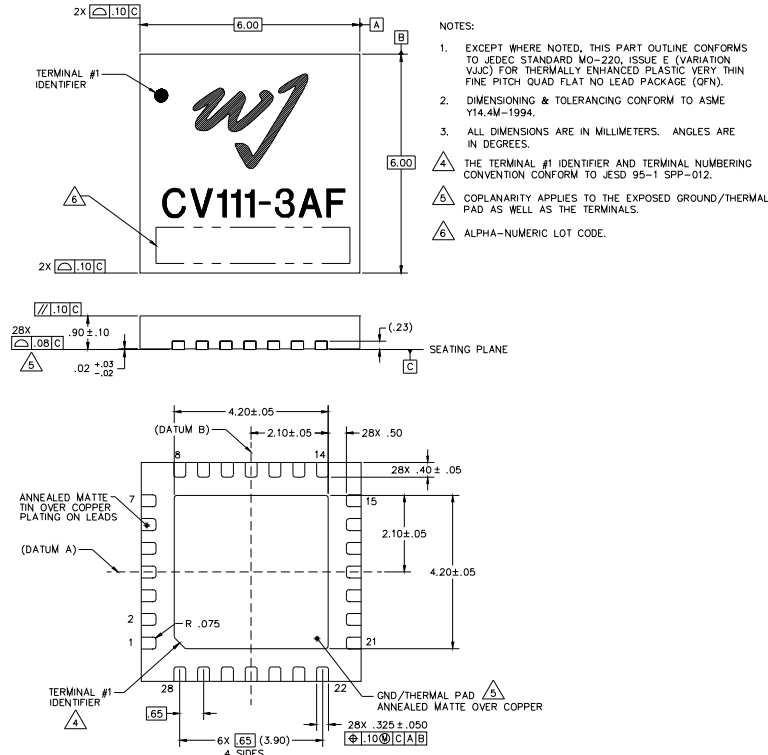
CV111-3A PCB75 供应商

UMTS-band High Linearity Downconverter

Mechanical Information

This package is lead-free/RoHS-compliant. The plating material on the pins is annealed matte tin over copper. It is compatible with both lead-free (maximum 260 °C reflow temperature) and leaded (maximum 245 °C reflow temperature) soldering processes.

Outline Drawing



Product Marking

The component will be lasermarked with a "CV111-3AF" product label with an alphanumeric lot code on the top surface of the package.

Tape and reel specifications for this part will be located on the website in the "Application Notes" section.

ESD / MSL Information



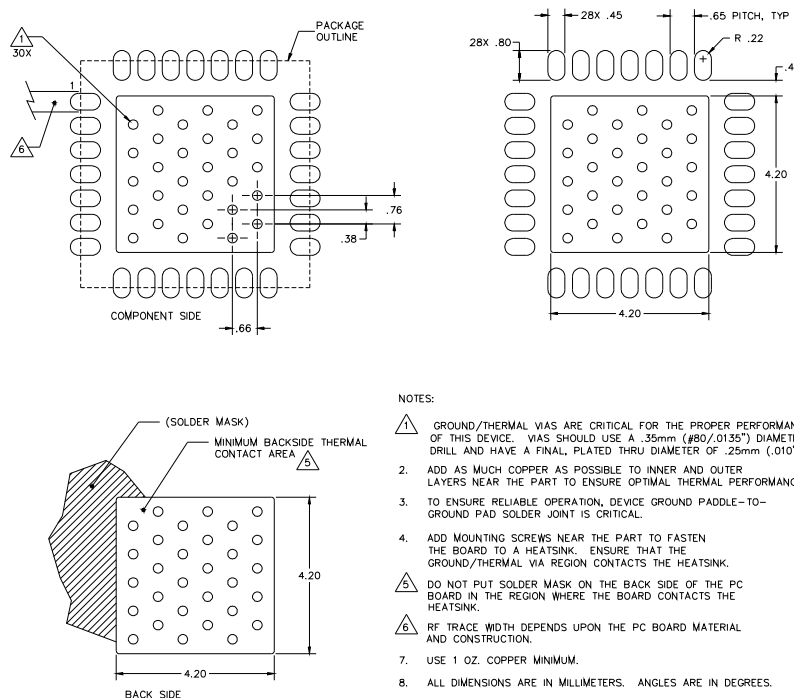
Caution! ESD sensitive device.

ESD Rating: Class 1B
 Value: Passes $\geq 500V$ to $<1000V$
 Test: Human Body Model (HBM)
 Standard: JEDEC Standard JESD22-A114

ESD Rating: Class III
 Value: Passes $\geq 500V$ to $<1000V$
 Test: Charged Device Model (CDM)
 Standard: JEDEC Standard JESD22-C101

MSL Rating: Level 2 at +260 °C convection reflow
 Standard: JEDEC Standard J-STD-020

Mounting Configuration / Land Pattern



Functional Pin Layout

Pin	Function	Pin	Function
1	RF Amp Output	15	LO Amp Input
2	GND	16	GND
3	N/C or GND	17	LO Amp Bias
4	GND	18	GND
5	N/C or GND	19	N/C or GND
6	GND	20	GND
7	Mixer RF Input	21	IF Amp Output/Bias
8	GND	22	GND
9	N/C or GND	23	IF Amp Input
10	GND	24	GND
11	Mixer LO Input	25	Mixer IF Output
12	GND	26	GND
13	LO Amp Output/Bias	27	RF Amp Input
14	GND	28	GND

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